

NOT RECOMMENDED FOR NEW DESIGN **USE DMN65**D8LDW



2N7002DWA

Product Summary

BV _{DSS}	R _{DS(ON)}	Package	I _D T _A = +25°C
60V	8Ω @ V _{GS} = 5V	SOT363	170mA
60 V	6Ω @ V _{GS} = 10V	301303	200mA

Description

This new generation MOSFET is designed to minimize the on-state resistance (R_{DS(ON)}), yet maintain superior switching performance, making it ideal for high-efficiency power management applications.

Applications

- DC-DC Converters
- **Power Management Functions**
- Battery Operated Systems and Solid-State Relays
- Drivers: Relays, Solenoids, Lamps, Hammers, Displays, Memories, Transistors, etc.

DUAL N-CHANNEL ENHANCEMENT MODE MOSFET

Features

- **Dual N-Channel MOSFET**
- Low On-Resistance
- Low Gate Threshold Voltage
- Low Input Capacitance
- Fast Switching Speed
- Small Surface Mount Package
- HBM Class 1C
- Totally Lead-Free & Fully RoHS Compliant (Notes 1 & 2)
- Halogen and Antimony Free. "Green" Device (Note 3)
- The 2N7002DWAQ is suitable for automotive applications requiring specific change control; it is AEC-Q101 qualified, PPAP capable, and manufactured in IATF 16949 certified facilities.
- https://www.diodes.com/quality/product-definitions/

Mechanical Data

- Case: SOT363
- Case Material: Molded Plastic. UL Flammability Classification Rating 94V-0
- Moisture Sensitivity: Level 1 per J-STD-020
- Terminals: Matte Tin Finish Annealed over Alloy 42 Leadframe Solderable per MIL-STD-202, Method 208 @3
- Terminal Connections: See Diagram
- Weight: 0.006 grams (Approximate)

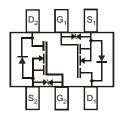
SOT363



HBM Class



Top View



Top View Internal Schematic

Ordering Information (Note 4)

Part Number	Compliance	Case	Packaging
2N7002DWA-7	Standard	SOT363	3,000/Tape & Reel
2N7002DWA-13	Standard	SOT363	10,000/Tape & Reel
2N7002DWAQ-7	Automotive	SOT363	3,000/Tape & Reel
2N7002DWAQ-13	Automotive	SOT363	10,000/Tape & Reel

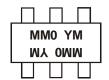
Notes:

- 1. No purposely added lead. Fully EU Directive 2002/95/EC (RoHS), 2011/65/EU (RoHS 2) & 2015/863/EU (RoHS 3) compliant.
- 2. See https://www.diodes.com/quality/lead-free/ for more information about Diodes Incorporated's definitions of Halogen- and Antimony-free, "Green" and Lead-free.
- 3. Halogen- and Antimony-free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and <1000ppm antimony compounds.
- 4. For packaging details, go to our website at https://www.diodes.com/design/support/packaging/diodes-packaging/.

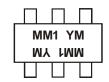
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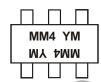
Marking Information



MM0 = Product Type Marking Code YM = Date Code Marking Y = Year (ex: E = 2017)M = Month (ex: 9 = September)



MM1 = Product Type Marking Code YM = Date Code Marking Y = Year (ex: E = 2017)M = Month (ex: 9 = September)



MM4 = Product Type Marking Code YM = Date Code Marking Y = Year (ex: E = 2017) M = Month (ex: 9 = September)

Date Code Key

Year	2012	-	20	17	2018	2019	2020	2021	20	22	2023	2024
Code	Z	-		Ε	F	G	Н	I	J		K	L
Month	Jan	Feb	Mar	Apr	May	Jun	Jul	Aug	Sep	Oct	Nov	Dec
Code	1	2	3	4	5	6	7	8	9	0	N	D

Maximum Ratings (@T_A = +25°C, unless otherwise specified.)

	Characteristic	,		Symbol	Value	Unit
Drain-Source Voltage				V _{DSS}	60	V
Gate-Source Voltage				V _{GSS}	±20	V
Continuous Drain Current (Note 5)	V _{GS} = 10V	Steady State	$T_A = +25$ °C $T_A = +70$ °C	lD	180 140	mA
Continuous Drain Current (Note 5)	V _{GS} = 5V	Steady State	$T_A = +25$ °C $T_A = +70$ °C	σ	150 120	mA
Continuous Drain Current (Note 6)	V _{GS} = 10V	Steady State	$T_A = +25^{\circ}C$ $T_A = +70^{\circ}C$	l _D	200 160	mA
Continuous Drain Current (Note 6)	V _{GS} = 5V	Steady State	$T_A = +25^{\circ}C$ $T_A = +70^{\circ}C$	ΙD	170 140	mA
Pulsed Drain Current (10µs Pulse, D	uty Cycle = 1%)			I _{DM}	700	mA

Thermal Characteristics

Characteristic	Symbol	Value	Unit
Total Power Dissipation (Note 5)	P_{D}	300	mW
Thermal Resistance, Junction to Ambient (Note 5)	$R_{ heta JA}$	435	°C/W
Total Power Dissipation (Note 6)	P_{D}	400	mW
Thermal Resistance, Junction to Ambient (Note 6)	$R_{ heta JA}$	330	°C/W
Thermal Resistance, Junction to Case (Note 6)	$R_{ heta JC}$	139	°C/W
Operating and Storage Temperature Range	T _J , T _{STG}	-55 to +150	°C

Notes:

- Device mounted on FR-4 PC board, with minimum recommended pad layout, single sided.
 Device mounted on FR-4 substrate PC board, 2oz copper, with 1inch square copper pad layout.

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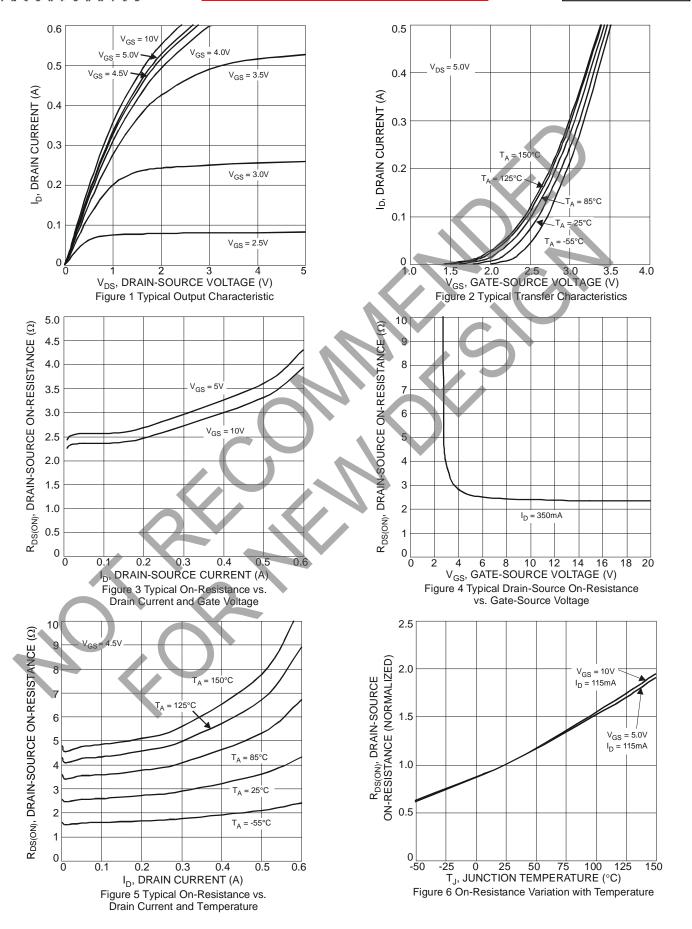
Electrical Characteristics (@T_A = +25°C, unless otherwise specified.)

Characteristic	Symbol	Min	Тур	Max	Unit	Test Condition
OFF CHARACTERISTICS (Note 7)						
Drain-Source Breakdown Voltage	BV _{DSS}	60		_	V	$V_{GS} = 0V, I_D = 250\mu A$
Zero Gate Voltage Drain Current	I _{DSS}	l	_	1.0	μΑ	$V_{DS} = 60V, V_{GS} = 0V$
Gate-Body Leakage	I _{GSS}		_	±5	μΑ	$V_{GS} = \pm 20V, V_{DS} = 0V$
ON CHARACTERISTICS (Note 7)						
Gate Threshold Voltage	V _{GS(TH)}	0.8	_	2.5	V	$V_{DS} = V_{GS}, I_{D} = 250 \mu A$
Static Drain-Source On-Resistance				8	Ω	$V_{GS} = 5.0V, I_D = 0.115A$
Static Diani-Source On-Resistance	R _{DS(ON)}	1	_	6	Ω	$V_{GS} = 10.0 V, I_D = 0.115 A$
Forward Transconductance	g FS	80	_	_	mS	$V_{DS} = 10V, I_D = 0.115A$
Diode Forward Voltage	V_{SD}		0.8	1.2	٧	$V_{GS} = 0V, I_S = 115mA$
DYNAMIC CHARACTERISTICS (Note 8)						
Input Capacitance	C _{iss}	l	22.0	_		
Output Capacitance	Coss	1	3.2	1	pF	$V_{DS} = 25V, V_{GS} = 0V, f = 1.0MHz$
Reverse Transfer Capacitance	C _{rss}		2.0	1		
Gate Resistance	R_{G}	l	88	1	Ω	$V_{DS} = 0V$, $V_{GS} = 0V$, $f = 1.0MHz$
Total Gate Charge V _{GS} = 10V	Q_g		0.87	I		
Total Gate Charge V _{GS} = 4.5V	Q_{g}	_	0.43		nC	$V_{GS} = 10V, V_{DS} = 30V,$
Gate-Source Charge	Q _{gs}	_	0.11			$I_D = 150 \text{mA}$
Gate-Drain Charge	Q_{gd}	1	0.11	_		
Turn-On Delay Time	t _{D(ON)}	1	3.3			
Turn-On Rise Time	t _R		3.2		nc	$V_{DD} = 30V, I_D = 0.115A, V_{GEN} = 10V,$
Turn-Off Delay Time	t _{D(OFF)}		12.0		ns	$R_{GEN} = 25\Omega$
Turn-Off Fall Time	t _F		6.3			

Notes:

Short duration pulse test used to minimize self-heating effect.
 Guaranteed by design. Not subject to production testing.







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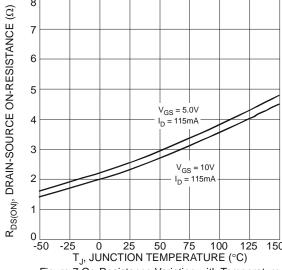
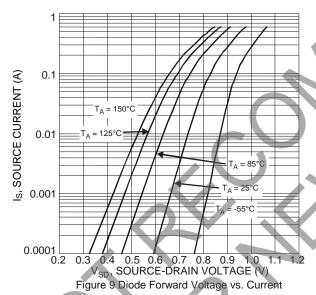


Figure 7 On-Resistance Variation with Temperature



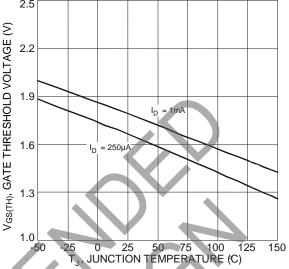
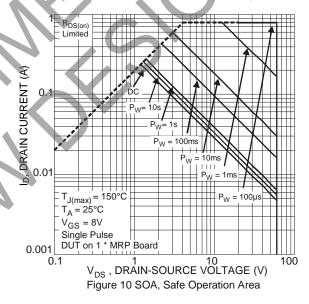


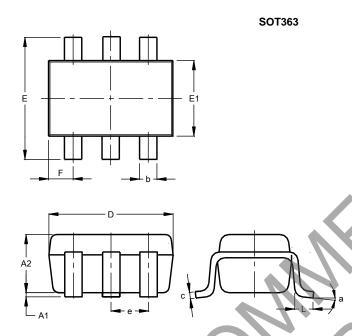
Figure 8 Gate Threshold Variation vs.Temperature





Package Outline Dimensions

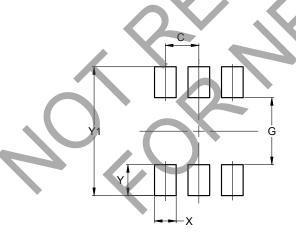
Please see http://www.diodes.com/package-outlines.html for the latest version.



SOT363							
Dim	Min	Max	Тур				
A1	0.00	0.10	0.05				
A2	0.90	1.00	1.00				
Ь	0.10	0.30	0.25				
O	0.10	0.22	0.11				
ð	1.80	2.20	2.15				
Е	2.00	2.20	2.10				
E1	1.15	1.35	1.30				
е	C	.650 B	SC				
F	0.40	0.45	0.425				
L	0.25	0.40	0.30				
a	0°	8°					
All Dimensions in mm							

Suggested Pad Layout

Please see http://www.diodes.com/package-outlines.html for the latest version.



Dimensions	Value (in mm)
С	0.650
G	1.300
Х	0.420
Y	0.600
V1	2 500

SOT363



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